

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)}$	I_D $T_A = +25^\circ C$
-60V	125m Ω @ $V_{GS} = -10V$	-4.3A
	190m Ω @ $V_{GS} = -4.5V$	-3.5A

Description

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Motor Control
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

Features and Benefits

- Fast Switching Speed
- Low Gate Drive
- Low Input Capacitance
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

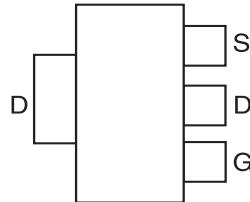
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208^(e3)
- Weight: 0.112 grams (Approximate)

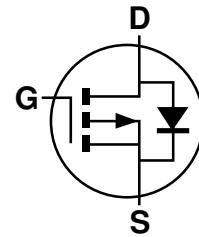
SOT223



Top View



Pin Out - Top View



Equivalent Circuit

Ordering Information (Notes 4 & 5)

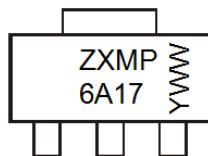
Part Number	Compliance	Case	Packaging
ZXMP6A17GQTA	Automotive	SOT223	1,000 / Tape & Reel

Note:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.
5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT223



ZXMP6A17 = Product Type Marking Code

YWW = Date Code Marking

Y or \bar{Y} = Year (ex: 5 = 2015)

WW or \bar{WW} = Week (01 - 53)

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V_{DSS}	-60	V	
Gate-Source Voltage		V_{GS}	± 20	V	
Continuous Drain Current	$V_{GS} = 10\text{V}$	(Note 7)	-4.3	A	
		$T_A = +70^\circ\text{C}$ (Note 7)	-3.5		
		(Note 6)	-3		
Pulsed Drain Current	$V_{GS} = 10\text{V}$	(Note 8)	I_{DM}	-13.7	A
Continuous Source Current (Body Diode)		(Note 7)	I_S	-4.8	A
Pulsed Source Current (Body Diode)		(Note 8)	I_{SM}	-13.7	A

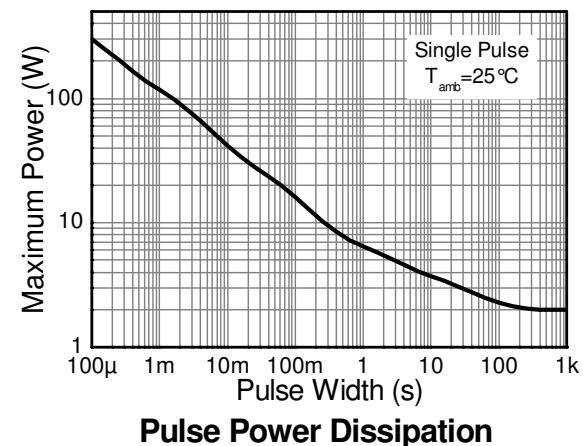
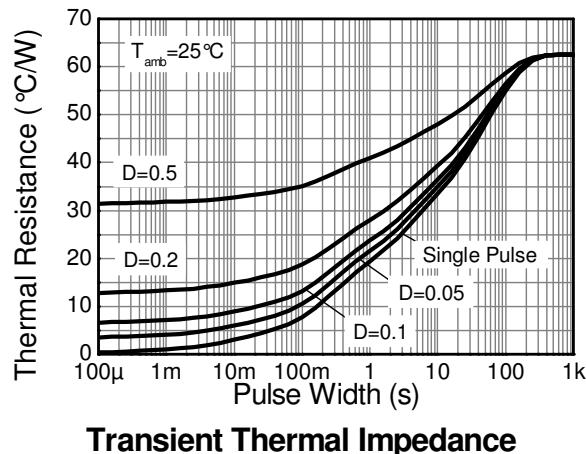
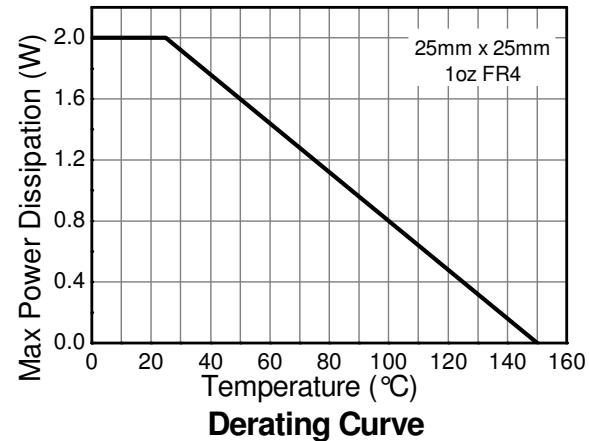
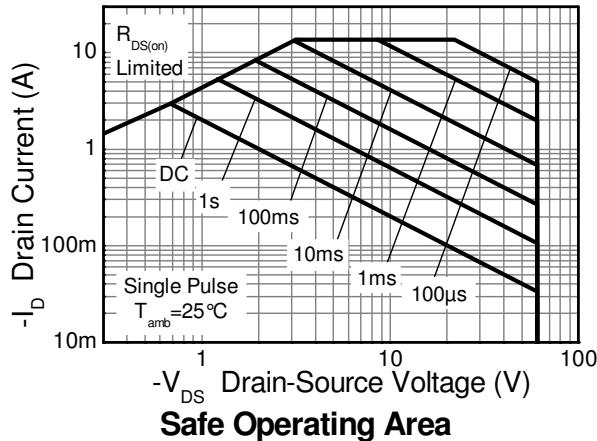
Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Note 6)	P_D	2	W mW/ $^\circ\text{C}$
	(Note 7)		16	
			3.9	
			31	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	62.5	$^\circ\text{C}/\text{W}$
	(Note 7)		32	
Thermal Resistance, Junction to Lead	(Note 9)	$R_{\theta JL}$	9.8	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Notes:

6. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
7. Same as Note 6, except the device is measured at $t \leq 10\text{sec}$.
8. Same as Note 6, except the device is pulsed with $D = 0.02$ and pulse width $300\mu\text{s}$. The pulse current is limited by the maximum junction temperature.
9. Thermal resistance from junction to solder-point (at the end of the drain lead).

Thermal Characteristics



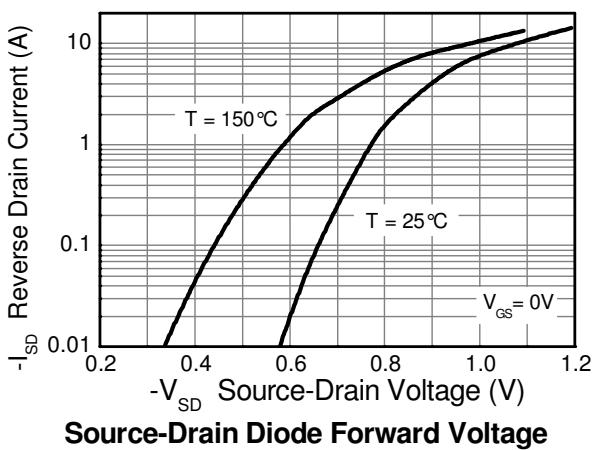
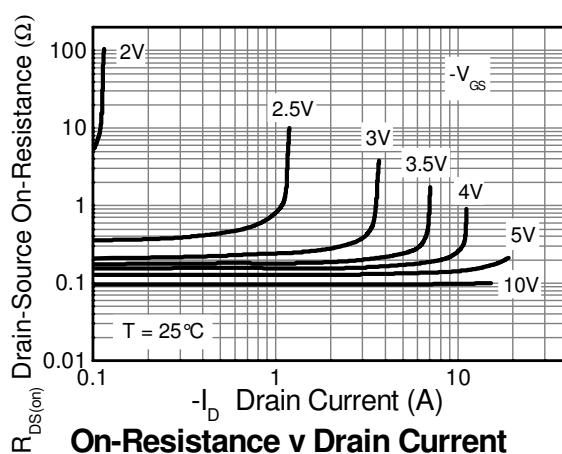
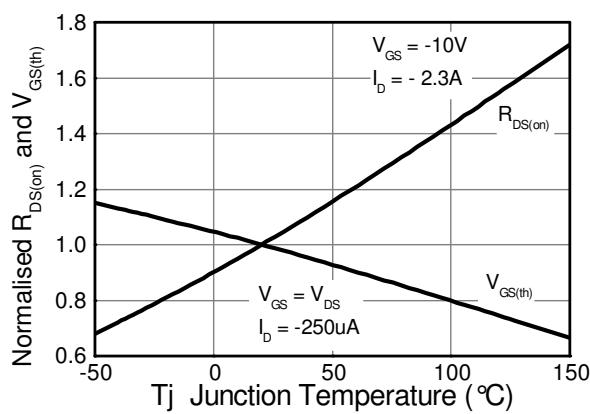
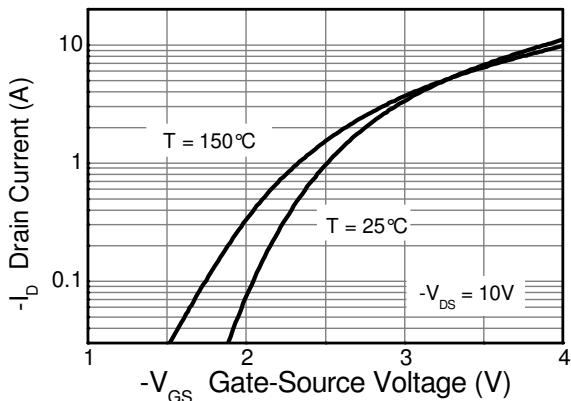
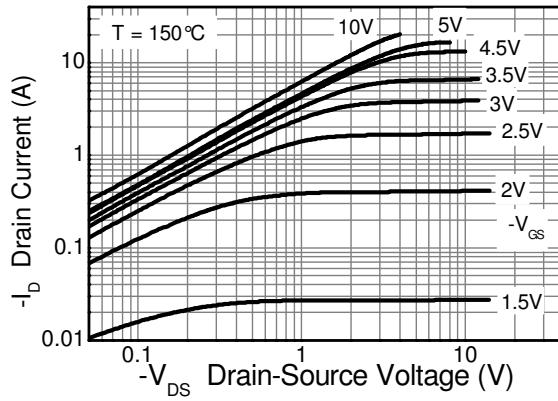
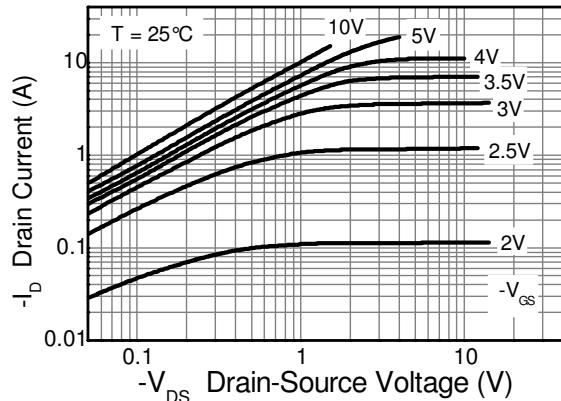
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	-60	—	—	V	$I_D = -250\mu\text{A}$, $V_{\text{GS}} = 0\text{V}$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-0.5	μA	$V_{\text{DS}} = -60\text{V}$, $V_{\text{GS}} = 0\text{V}$
Gate-Source Leakage	I_{GSS}	—	—	± 100	nA	$V_{\text{GS}} = \pm 20\text{V}$, $V_{\text{DS}} = 0\text{V}$
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	-1	—	—	V	$I_D = -250\mu\text{A}$, $V_{\text{DS}} = V_{\text{GS}}$
Static Drain-Source On-Resistance (Note 10)	$R_{\text{DS}(\text{ON})}$	—	0.096	0.125	Ω	$V_{\text{GS}} = -10\text{V}$, $I_D = -2.2\text{A}$
			0.12	0.19		$V_{\text{GS}} = -4.5\text{V}$, $I_D = -1.8\text{A}$
Forward Transconductance (Notes 10 & 11)	g_{fs}	—	4.7	—	S	$V_{\text{DS}} = -15\text{V}$, $I_D = -2.2\text{A}$
Diode Forward Voltage (Note 10)	V_{SD}	—	-0.85	-0.95	V	$I_S = -2\text{A}$, $V_{\text{GS}} = 0\text{V}$, $T_J = +25^\circ\text{C}$
Reverse Recovery Time (Note 11)	t_{rr}	—	25.1	—	ns	$I_S = -1.7\text{A}$, $dI/dt = 100\text{A}/\mu\text{s}$,
Reverse Recovery Charge (Note 11)	Q_{rr}	—	27.2	—	nC	$T_J = +25^\circ\text{C}$
DYNAMIC CHARACTERISTICS (Note 11)						
Input Capacitance	C_{iss}	—	637	—	pF	$V_{\text{DS}} = -30\text{V}$, $V_{\text{GS}} = 0\text{V}$ $f = 1\text{MHz}$
Output Capacitance	C_{oss}	—	70	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	53	—	pF	
Total Gate Charge (Note 12)	Q_g	—	9	—	nC	$V_{\text{GS}} = -4.5\text{V}$
Total Gate Charge (Note 12)	Q_g	—	17.7	—	nC	$V_{\text{DS}} = -30\text{V}$ $V_{\text{GS}} = -10\text{V}$ $I_D = -2.2\text{A}$
Gate-Source Charge (Note 12)	Q_{gs}	—	1.6	—	nC	
Gate-Drain Charge (Note 12)	Q_{gd}	—	4.4	—	nC	
Turn-On Delay Time (Note 12)	$t_{\text{D}(\text{on})}$	—	2.6	—	ns	$V_{\text{DD}} = -30\text{V}$, $V_{\text{GS}} = -10\text{V}$ $I_D = -1\text{A}$, $R_G \geq 6\Omega$
Turn-On Rise Time (Note 12)	t_r	—	3.4	—	ns	
Turn-Off Delay Time (Note 12)	$t_{\text{D}(\text{off})}$	—	26.2	—	ns	
Turn-Off Fall Time (Note 12)	t_f	—	11.3	—	ns	

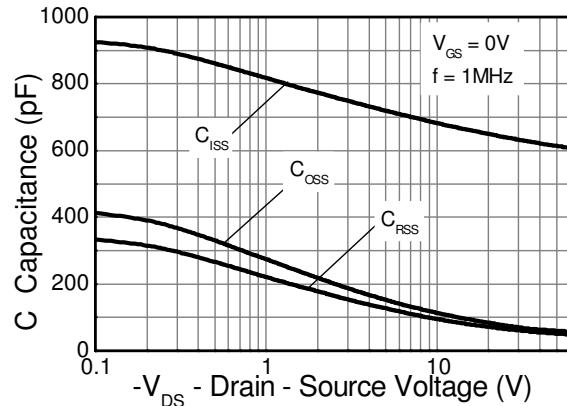
Notes:

10. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$; duty cycle $\leq 2\%$.
11. For design aid only, not subject to production testing.
12. Switching characteristics are independent of operating junction temperatures.

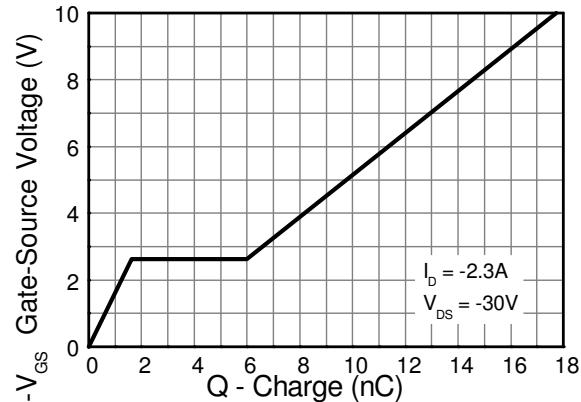
Typical Characteristics



Typical Characteristics (continued)

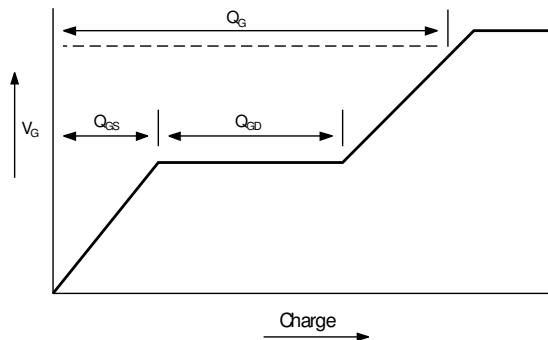


Capacitance v Drain-Source Voltage

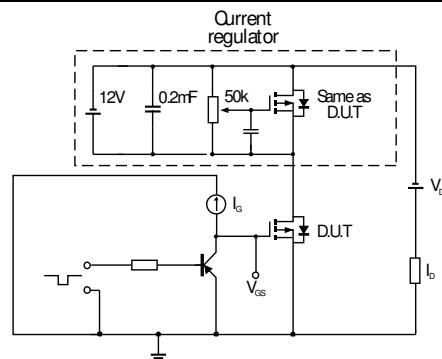


Gate-Source Voltage v Gate Charge

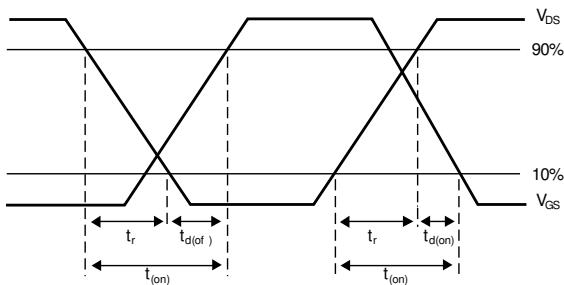
Test Circuits



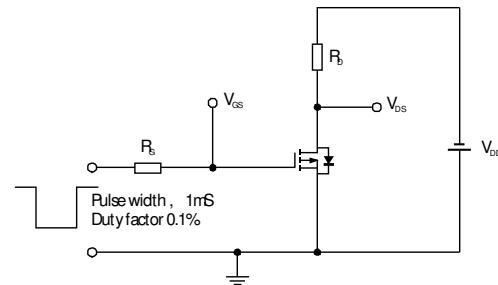
Basic gate charge waveform



Gate charge test circuit



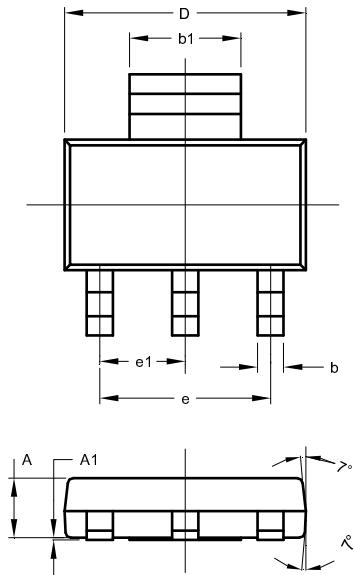
Switching time waveforms



Switching time test circuit

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

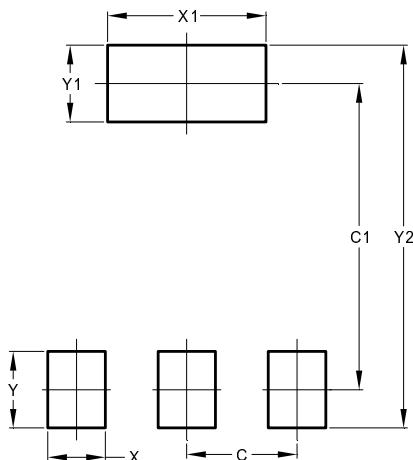


SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com